

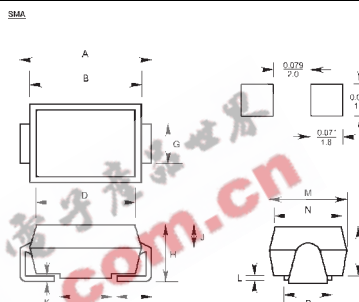


SS1A THRU SS1M

SURFACE MOUNT SUPER FAST RECOVERY RECTIFIER
Reverse Voltage - 50 to 1000 Volts
Forward Current - 1.0 Ampere

Features

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Superfast recovery times for high efficiency
- Plastic package has Underwriters Laboratory Flammability classification 94V-0
- High temperature soldering:
260°C/10 seconds at terminals



Mechanical Data

- **Case:** SMA Molded plastic
- **Terminals:** Solder plated solderable per MIL-STD-750, method 2026
- **Polarity:** Indicated by cathode band
- **Weight:** 0.004 ounce, 0.11 gram

DIMENSIONS					
DIM	inches		mm		Note
	Min.	Max.	Min.	Max.	
A	0.216	0.226	5.48	5.74	
B	0.176	0.182	4.48	4.63	
C	0.094	0.100	2.40	2.55	
D	0.170	0.176	4.33	4.48	
E	0.039	0.055	1.00	1.40	
F	0.080	0.081	2.03	2.07	
G	0.068	0.083	1.72	2.10	
H	0.112	0.118	2.85	3.00	
J	0.057	-	1.44	-	
K	-	0.018	-	0.45	
L	0.016	-	0.40	-	
M	0.109	0.115	2.77	2.93	
N	0.105	0.107	2.67	2.73	
P	0.078	0.081	2.00	2.05	

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	SS1A	SS1B	SS1C	SS1D	SS1E	SS1G	SS1J	SS1K	SS1M	Units
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	600	800	1000	Volts
Maximum average forward rectified current at T _L =100°C	I _(AV)	1.0									Amp
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	I _{FSM}	30.0									Amps
Maximum instantaneous forward voltage at 1.0A	V _F	0.95				1.25		1.40			Volts
Maximum DC reverse current at rated DC blocking voltage T _A =25°C T _A =100°C	I _R					5.0 500.0					μ A
Maximum reverse recovery time (Note 1)	T _{rr}					35.0					nS
Typical junction capacitance (Note 2)	C _J					10.0					p F
Typical thermal resistance (Note 3)	R _{θJL}					35.0					°C/W
Operating and storage temperature range	T _J , T _{STG}	-50 to +150									°C

Notes:

- (1) Reverse recovery test conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$
- (2) Measured at 1.0MHz and applied reverse voltage of 4.0 volts
- (3) 8mm² (0.013mm thick) land areas

RATINGS AND CHARACTERISTIC CURVES

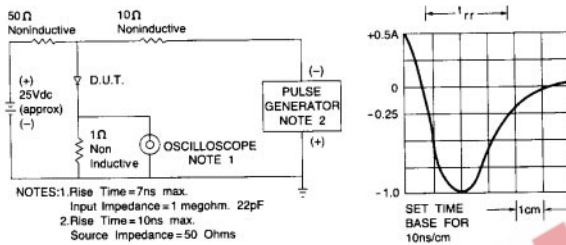


Fig. 1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM ES1A THRU ES1G

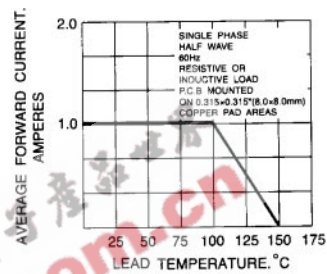


Fig. 2 - MAXIMUM AVERAGE FORWARD CURRENT RATING

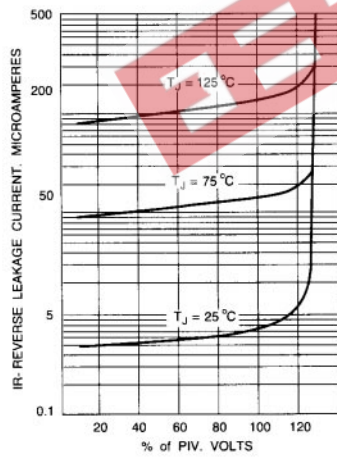


Fig. 3 - TYPICAL REVERSE CHARACTERISTICS

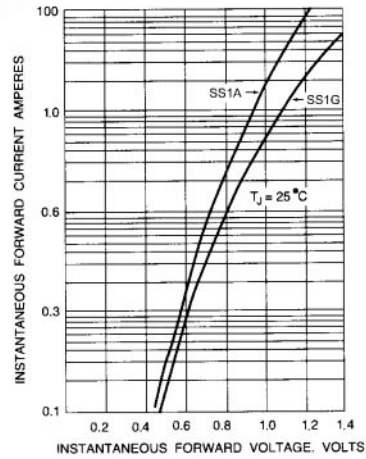


Fig. 4 - TYPICAL JUNCTION CAPACITANCE

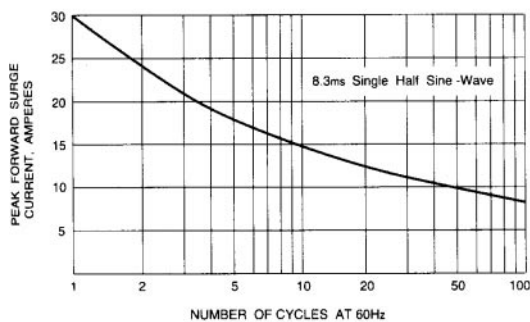


Fig. 5 - MAXIMUM NON-REPETITIVE SURGE CURRENT

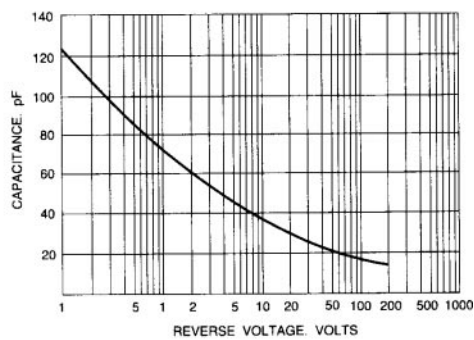


Fig. 6 - TYPICAL JUNCTION CAPACITANCE